The effect of Nb on the corrosion and hydrogen pick-up of Zr alloys

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$\log_{10}[D]$ (per ZrO$_2$)

Electrons

-30 -25 -20 -15 -10 -5  0

$\log_{10}P_{O_2}$/atm

-10 -8 -6 -4 -2 0

Holes

-10 -8 -6 -4 -2 0

$V_0^*$

$V_0^x$

$V_{Zr}^*$

$Nb_{Zr}$

$Nb_{Zr}^x$

$V_{Zr}^{***}$
The effect of Nb on the corrosion and hydrogen pick-up of Zr alloys

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Abstract

Zr-Nb alloys are known to perform better in corrosion and hydrogen pick-up than other Zr alloys but the mechanism by which this happens is not well understood. Atomistic simulations using density functional theory of both tetragonal and monoclinic ZrO\textsubscript{2} were performed, with intrinsic defects and Nb dopants. The overall defect populations with respect to oxygen partial pressure were calculated and presented in the form of Brouwer diagrams. Nb is found to favour 5+ in monoclinic ZrO\textsubscript{2} at all partial pressures, but can exist in oxidation states ranging from 5+ to 3+ in the tetragonal phase. Nb\textsuperscript{5+} is charge balanced by Zr vacancies in both phases, suggesting that contrary to previous assumptions, Nb does not act as an n-type dopant in the oxide layer. Clusters containing oxygen vacancies were considered, Nb\textsuperscript{2+} was shown to exist in the tetragonal phase with a binding energy of 2.4 eV. This supports the proposed mechanism whereby low oxidation state Nb ions (2+ or 3+) charge balance the build-up of positive space-charge in the oxide layer, increasing oxygen vacancy and electron mobility, leading to near-parabolic corrosion kinetics and a reduced hydrogen pick-up. Previous experimental
work has shown that tetragonal ZrO$_2$ transforms to the monoclinic phase during transition, and that during transition a sharp drop in the instantaneous hydrogen pick-up fraction occurs. The oxidation of lower charge state Nb defects to Nb$^{5+}$ during this phase change, and the consequent temporary n-doping of the oxide layer, is proposed as an explanation for the drop in hydrogen pick-up during transition.

Keywords:
Density functional theory, Zirconium, Niobium, Corrosion, Hydrogen pick-up

1. Introduction

Zirconium is used as a cladding material for water-cooled reactors due to its good thermal and mechanical properties and low absorption of thermal neutrons. With the recent drive towards higher fuel burn-ups and therefore increased in-reactor fuel lifetimes, long term corrosion resistance and the absorption, by the cladding, of hydrogen produced during corrosion have become increasingly important [1]. As the solubility limit for H in Zr is exceeded, Zr-hydrides precipitate in the cladding alloy leading to cladding embrittlement [2, 3]. This problem is particularly apparent after removal from the reactor; as the cladding cools, the hydrogen solubility drops and further brittle Zr-hydrides precipitate, which can lead to delayed hydride cracking [4]. Thus, increasing corrosion resistance and reducing the hydrogen pick-up fraction (HPUF) of fuel cladding are key aims for cladding alloy manufacturers.

The Zr alloys of choice in most current water-cooled reactor designs con-
tain 0.5-2.5 wt. % Nb due to its beneficial effect on HPUF [5, 6, 7]. Long term autoclave studies have demonstrated that Zr-2.5Nb exhibits near parabolic corrosion kinetics, and a lower corrosion rate than other Zr-based alloys such as Zircaloy-4 and Sn-containing alloys such as ZIRLO, as shown in Figure 1. The reason for this improved corrosion behaviour is not fully understood, however, it has previously been suggested that in the oxide layer, Nb exists almost exclusively in a 5+ oxidation state as a substitutional defect on a Zr site. This is assumed to be charge compensated by a suppression of oxygen vacancies, lowering the oxygen ion conductivity of the oxide layer and thus lowering the oxidation rate [8]. This has also been suggested as a reason for the decreased HPUF in Nb-containing alloys; the Nb\(^{5+}\) ion is expected to act as an n-type dopant, donating electrons to the oxide layer. The additional electrons combine with H\(^+\) ions closer to the oxide/water interface, forming H\(_2\) gas which can then escape into the water instead of the cladding metal [9, 10].

The assumption that Nb exists only in the 5+ charge state in the oxide layer is supported by previous DFT simulation work [11]. However, several independent x-ray absorption near-edge spectroscopy (XANES) studies have identified oxidation states ranging from 5+ to 2+ (and also metallic Nb) in the oxide layer of Zr-Nb alloys [12, 13, 14, 15, 16]. Recently there has been some debate regarding the location of these lower charge state Nb ions (i.e. whether they exist within the bulk oxide, or are localised in the partially oxidised Nb-containing secondary phase precipitates (SPPs) [17], the latter is reasonable, since SPPs account for around 60% of the Nb in a typical Zr-1.0Nb alloy such as ZIRLO). However, a recent study by Couet et al. [16]
Figure 1: Corrosion of Zry-4, ZIRLO and Zr-2.5%Nb at 360 °C in de-ionised water under saturated pressure conditions at 18.7 MPa, reproduced from [7].
investigated an alloy with a sufficiently low Nb-concentration to avoid the formation of SPPs (Zr-0.4Nb), which showed that a large proportion of the Nb contained in the oxide layer was in a 3+ oxidation state or below. The assumption that Nb$^{5+}$ is the only Nb ion present in the oxide layer is also unable to explain the variation in HPUF observed during corrosion [18].

The corrosion model developed by Wagner and Hauffe [19, 20] suggests that all Zr-based alloys should exhibit parabolic corrosion kinetics, however, this is rarely observed in experimental studies. A recent corrosion model developed by Couet et al. [16] applies the space charge model to the oxide layer of Zr-alloys and demonstrated that during corrosion, the limited mobility of oxygen vacancies, when compared to electrons, could lead to a build-up of non-equilibrium positive charge in the layer, inhibiting corrosion and causing sub-parabolic kinetics. This build-up of charge also inhibits the movement of electrons, reducing the electrical conductivity of the oxide and thus increasing HPUF. In Zr-Nb alloys, it is proposed that the ability of Nb to occupy charge states lower than Zr$^{4+}$ (i.e. to be included as overall negatively charged defects) may help mitigate the build-up of space charge, allowing near-parabolic corrosion kinetics and reducing HPUF.

The Nb-containing alloy ZIRLO exhibits near parabolic corrosion kinetics, almost identical to that of Zr-2.5Nb, but with a first transition time similar to Zircaloy-4. This reduced transition time has recently been linked to the presence of Sn in the alloy composition [21, 22]. Previous investigations have considered the oxide layer to be a generally uniform structure, making no distinction between the monoclinic and tetragonal phases of ZrO$_2$ that have been shown to be present [23, 24]. In this study, DFT simulations
are used to study both isolated defects and clustering of Nb defects with oxygen vacancies in both tetragonal and monoclinic ZrO$_2$, to determine the possible charge states and infer a possible corrosion mechanism.

2. Methodology

Simulations were performed using the DFT code CASTEP 8.0 [25], with consistent parameters and convergence criteria used throughout. Ultra-soft pseudo potentials with a cut-off energy of 550 eV were used, and the Perdew, Burke and Ernzerhof (PBE) [26] formulation of the generalised gradient approximation (GGA) was used to describe the exchange-correlation functional, since previous work has shown this to effectively describe Zr systems [22, 46, 27, 28, 4]. A k-point separation of 0.045 Å$^{-1}$ arranged in a Monkhorst-Pack sampling scheme [29] and supercells formed $3 \times 3 \times 2$ repetitions of the tetragonal ZrO$_2$ unit cell and $2 \times 2 \times 2$ repetitions of the monoclinic ZrO$_2$ unit cell in the x, y and z directions respectively, were shown to offer an acceptable compromise between simulation accuracy and computation time. An energy correction calculated using the screened Madelung method [31] was used to account for the electrostatic self-interaction of defects created by the use of periodic boundary conditions and a finite supercell size. This is an improvement over the Makov-Payne method [32] as it takes into account the anisotropy of the dielectric properties of the two structures. The dielectric values calculated by Zhao and Vanderbilt [33] were used.

All defective structures were simulated using pre-relaxed pure ZrO$_2$ supercells, which were then energy minimised under constant volume. The criterion for energy convergence in self-consistent calculations was $1 \times 10^{-8}$ eV.
The energy and displacement limits between successive iterations for each ion were $1 \times 10^{-5}$ eV and $5 \times 10^{-4}$ Å respectively, and a maximum force of $1 \times 10^{-2}$ eV/Å between ions was allowed for convergence to be considered achieved.

For the Nb-containing simulations in this work, a +U value of 1.5 eV was applied in order to account for the errors arising from the use of the PBE formulation of the GGA exchange-correlation functional. This value was taken from an extensive study into the behaviour of transition metals using DFT with comparisons to experimental energies, performed by Hau-tier et al. [34]. In this approach we follow extensive previous work using the +U parameter to account for errors simulating transition metal oxides in DFT [35, 36, 37, 11, 38].

Defect formation energies ($E_f$) were calculated using the method outlined in [22]. All vacancy, substitutional and interstitial defects were considered (anti-site defects were not considered due to the large size and charge difference between the anions and cations). The chemical potentials of the reactive species used to plot the Brouwer diagrams were obtained from formation energies of the relevant oxides following established methods [39, 40, 41, 42, 22].

In order to ensure charge neutrality, the sum of all defects multiplied by their charge must equal zero:

$$\sum_i q_i c_i - N_c \exp \left( -\frac{E_g - \mu_e}{k_B T} \right) + N_v \exp \left( -\frac{\mu_e}{k_B T} \right) = 0$$

(1)

where the first term is the sum of the charges of all ionic defects ($q_i$ is the charge and $c_i$ the concentration of defect $i$), the second and third terms are the electron and hole concentrations respectively. $N_c$ and $N_v$ are the density.
of states for the conduction and valence bands, $E_g$ is the band gap of the crystal, $k_B$ is the Boltzmann constant and $T$ the temperature. The concentrations $c_i$ of each defect $i$ are calculated using the approach developed by Kasamatsu et al. [43], which uses standard Boltzmann statistics to calculate concentrations but also accounts for defects competing for the same lattice site.

Tetragonal ZrO$_2$ is a wide band gap insulator, and as such the concentrations of electrons and holes are expected to be sufficiently low that Boltzmann statistics are appropriate. Self-trapping of electrons will cause a reduction in the formation energy of electrons in the conduction band, when compared to the value calculated by $E_g - \mu_e$, however due to the wide band gap the difference in energy will be minimal and so this is an acceptable approximation [41].

Using the relationship in Equation 1, the electron chemical potential required to ensure charge neutrality for a given set of chemical potentials and oxygen partial pressure, and thus the concentration of defects, can be calculated. By plotting the defect concentration as a function of oxygen partial pressure a Brouwer diagram can be constructed. Oxygen partial pressure in the oxide layer decreases with distance from the oxide/water interface, and thus a Brouwer diagram can provide insight into the defect concentrations through the thickness of the oxide, with the x-axis analogous to moving, with increasing $P_{O_2}$, from the metal/oxide interface (low $P_{O_2}$) towards the oxide/water interface (high $P_{O_2}$). For all diagrams, the DFT predicted band gaps of 3.40 eV for the monoclinic phase and 3.95 eV for the tetragonal phase were used.
In order to investigate the behaviour of defects under non-equilibrium charge conditions (space charge), equation 1 was modified:

\[ \sum_i q_i c_i - N_c \exp \left( - \frac{E_g - \mu_e}{k_B T} \right) + N_v \exp \left( - \frac{\mu_e}{k_B T} \right) = q_{sc} \]  

(2)

where \( q_{sc} \) is the concentration of space charge. Unlike the localised effects expected in real oxides, this will result in the application of a constant space charge across the whole range of partial pressures, however by considering charge concentrations at a level comparable to that in real oxides, insights into the effects can be gained.

3. Results and Discussion

The predicted defect formation energies under atmospheric oxygen partial pressure (0.2 atm) plotted across the experimental band gap of 5.75 eV are shown in Figure 2. In the monoclinic phase, Nb\(^{\bullet}\)Zr is favoured close to the valance band maximum (VBM), transitioning through all oxidation states with increasing \( \mu_e \) with Nb\(^{\prime\prime}\)Zr favoured close to the conduction band minimum (CBM). In the tetragonal phase, Nb\(^{\bullet}\)Zr is also favoured close to the VBM, however this transitions directly to Nb\(^{\prime}\)Zr approximately half way across the band gap and remains the favoured defect up to the CBM, this result is in excellent agreement with previous DFT work performed by Otgonbataar et al. [11].

Figure 3a shows the predicted intrinsic defects in monoclinic ZrO\(_2\), plotted at a temperature of 635 K using the band gap predicted by DFT. Fully charged Zr vacancies (V\(^{\prime\prime\prime}\)Zr) charge balanced by holes dominate at high oxygen partial pressures, however below 10\(^{-18}\) atm, electrons and holes are the dominant species. In the tetragonal phase (Figure 3b), the increased temperature
Figure 2: Formation energies of Nb substitutional defects, in (a) monoclinic and (b) tetragonal ZrO$_2$ plotted from the VBM across the experimental band gap of 5.75 eV [44].
Figure 3: Brouwer diagram showing the concentrations of point defects in (a) intrinsic m-ZrO$_2$ at 635 K and (b) intrinsic t-ZrO$_2$ at 1500 K plotted as a function of oxygen partial pressure with DFT predicted band gaps of (a) 3.40 eV and (b) 3.90 eV.

of 1500 K used to generate the diagram leads to significantly higher intrinsic defect concentrations. Nevertheless at high oxygen partial pressures the $V'''_{Zr}$ is again dominant, charge balanced by holes, although below $10^{-10}$ atm, $V''_{O}$, charge compensated by electrons, becomes dominant.

The elevated temperature of 1500 K was used for the tetragonal phase simulations to account for the lack of stress stabilisation in the simulations, which is present in the oxide layer. In this we follow an approach used previously [45, 11, 22, 46], however concern remains that the intrinsic defect concentration predicted in these high temperature diagrams may be excessive.
Figure 4: Brouwer diagram showing the concentrations of point defects in (a) m-ZrO$_2$ and (b) t-ZrO$_2$ containing Nb at a concentration of $0.5 \times 10^{-2}$ (per ZrO$_2$) as a function of oxygen partial pressure at 635 K, plotted with band gaps of (a) 3.40 eV and (b) 3.90 eV. DFT simulations were performed with a $+U$ value of 1.5 eV applied to Nb.

Figure 4a shows the predicted defect concentrations of m-ZrO$_2$ at 635 K containing Nb at a concentration of $0.5 \times 10^{-2}$ (per ZrO$_2$). As shown in Figure 3a, the concentrations of intrinsic defects in pure m-ZrO$_2$ are extremely low, and as such Nb defects dominate the doped system. Nb$_{Zr}^*$ is the dominant defect across all oxygen partial pressures, charge balanced by V$^{''''}_{Zr}$. At low oxygen partial pressures, Nb$_{Zr}^{''}$ and electrons begin to appear, however neither becomes dominant over the partial pressures considered. Clusters of Nb with an oxygen vacancy were simulated for the monoclinic phase, however none appeared in concentrations higher than $10^{-10}$ per ZrO$_2$. Despite applying space charge concentrations far higher than would be expected in the oxide layer [16], Nb$_{Zr}^*$ remained the dominant defect in m-ZrO$_2$ across all oxygen partial pressures, with alternate charge states predicted to be several orders of magnitude lower in concentration. This suggests that the Nb ions in charge states lower than 5+ are unlikely to be present as defects in the monoclinic...
phase. While this result agrees with previous assumptions that the 5+ oxidation state is ubiquitous in the monoclinic layer, the diagrams suggest that Zr vacancies are the preferred charge balancing mechanism. This is highly significant as it suggests that, despite fully oxidising to the 5+ state, Nb does not act as an n-type dopant and thus the electrical conductivity of the oxide layer will not increase. Conductivity measurement such as those performed in the study of Nb-doping of TiO$_2$ by Baumard and Tani [47], which demonstrated the n-type doping properties of Nb in that system, would offer insight into the predictions made based on the current work. An increase in electrical conductivity has previously been assumed to be the primary reason for the reduced HPUF observed in Nb-containing Zr alloys, however this result suggests that another mechanism is responsible.

In the tetragonal phase at 635 K, as shown in Figure 4b, Nb$_\mathbf{Zr}$ is again predicted to be dominant across all oxygen partial pressures. However, as previously discussed, the tetragonal phase is not thermodynamically stable at 635 K without additional forms of stabilisation, and so since stress was not included in the simulations, higher temperatures were considered.
Figure 5: Brouwer diagram showing the concentrations of point defects in t-ZrO$_2$ plotted with the DFT predicted band gap of 3.90 eV and containing Nb at a concentration of $0.5 \times 10^{-2}$ (per ZrO$_2$) as a function of oxygen partial pressure at 1500 K. Due to the complexity of the diagram, the defect types have been labelled on separate, identical figures: (a) intrinsic defects, (b) Nb$_{Zr}$ isolated defects, (c) \{Nb$_{Zr}$: V$_O$\} type defect clusters and (d) \{Nb$_{Zr}$: V$_O$::Nb$_{Zr}$\} type defect clusters. DFT simulations were performed with a $+U$ value of 1.5 eV applied to Nb.

Figure 5 shows the predicted defect behaviour for Nb in tetragonal ZrO$_2$. At high temperature, the isolated defect behaviour (Figure 5b) shows that while Nb$_{Zr}^*$ is dominant across most partial pressures, below $\sim 10^{-30}$ atm Nb$_{Zr}^\prime$ becomes dominant. Nb$_{Zr}^\prime$ also appears at lower partial pressures, but is not the dominant defect type at any partial pressure considered.
Defect clusters containing Nb and an oxygen vacancy were simulated and included in the Brouwer diagram for tetragonal ZrO$_2$. Due to the wide variety of possible oxidation states available to Nb, two different cluster arrangements with a variety of overall charges were considered. It is assumed that oxygen vacancies always assume the fully charged state (V$_{O}^{••}$), and thus;

$\{Nb_{Zr}:V_O\}$ with overall charges between 0 and 3+ allow Nb to assume states between 2+ and 5+, and $\{Nb_{Zr}:V_O:Nb_{Zr}\}$ between -2 and +2, allowing a variety of oxidation states between 3+ and 5+ for the Nb ions. The assumption that all oxygen vacancies are in the fully charged state is consistent with the overall spin of the defective structures shown in Table 1; Nb'$_{Zr}$ and Nb''$_{Zr}$ have 3 and 1 valence electrons remaining resulting in both defects having an unpaired outer shell electron, and thus an overall spin, Nb'$_{Zr}$ and Nb''$_{Zr}$ have 2 and 0 valence electrons remaining, and thus no overall spin. The agreement of the overall spin in Table 1 with the electronic structure for the predicted Nb defects is strong evidence that all of the clusters contain V$_{O}^{••}$ and that the Nb defect is solely responsible for the overall charge difference.

Figure 5d suggests that $\{Nb_{Zr}:V_O:Nb_{Zr}\}$ type clusters are unlikely to form in significant concentrations, however Figure 5c suggests that $\{Nb_{Zr}:V_O\}$ type clusters may be important. At the lowest partial pressure considered ($10^{-35}$ atm), $\{Nb'_{Zr}:V_{O}^{•}\}$ and $\{Nb''_{Zr}:V_{O}^{••}\}$ are predicted to be present in concentrations of $1 \times 10^{-4}$ per ZrO$_2$. Following the assumption that the oxygen vacancies in these clusters will occupy a 2+ oxidation state, these two clusters contain Nb'$_{Zr}$ and Nb''$_{Zr}$ respectively. This represents the first time that Nb has been observed in DFT simulations of ZrO$_2$ in the 2+ oxidation state, a result that has been observed in multiple XANES experimental stud-
ies as detailed previously. This suggests that \( \{\text{Nb}_{\text{Zr}}: V_{\text{O}}\} \) defect clustering may occur in the oxide layer, as isolated Nb defects have not been predicted to assume the 2+ oxidation state.

Table 1 shows the binding energies of the \( \{\text{Nb}_{\text{Zr}}: V_{\text{O}}\} \) type clusters in t-ZrO\(_2\). \( \{\text{Nb}_{\text{Zr}}^\text{′′}: V_{\text{O}}^{\text{***}}\}^\times \), which contains Nb\(^{2+}\), shows a strongly favourable binding energy, suggesting that, if able to form, this cluster would be very stable and would exist as long as the Nb\(^{2+}\) ion is favourable. This is significant, as Nb\(^{***}\) is not predicted to exist as an isolated defect, and as such Nb\(^{2+}\) can only exist in a cluster. Also shown in Table 1 is the overall spin on the system as calculated by DFT. The results suggest that the \( \{\text{Nb}_{\text{Zr}}^\text{′′}: V_{\text{O}}^{\text{***}}\}^\times \) and \( \{\text{Nb}_{\text{Zr}}^\text{′}: V_{\text{O}}^{\text{***}}\}^{\text{**}} \) defects both contain an unpaired valence electron, this is as expected as these clusters would require the Nb ion to have donated 1 and 3 electrons respectively. The remaining defect clusters all exhibit small binding energies, with \( \{\text{Nb}_{\text{Zr}}^\text{′}: V_{\text{O}}^{\text{***}}\}^{\text{**}} \) slightly negative (favourable) and the remaining two positive (unfavourable). These results may suggest that the presence of an unpaired valence electron in the electronic structure of the Nb ion causes a slight preference to form a cluster.

<table>
<thead>
<tr>
<th>Cluster</th>
<th>Energy (eV)</th>
<th>Spin</th>
</tr>
</thead>
<tbody>
<tr>
<td>( {\text{Nb}<em>{\text{Zr}}^\text{′′}: V</em>{\text{O}}^{\text{***}}}^\times )</td>
<td>-2.36</td>
<td>-1.00</td>
</tr>
<tr>
<td>( {\text{Nb}<em>{\text{Zr}}^\text{′}: V</em>{\text{O}}^{\text{*<strong>}}}^{\text{</strong>}} )</td>
<td>0.24</td>
<td>0.01</td>
</tr>
<tr>
<td>( {\text{Nb}<em>{\text{Zr}}^\text{′}: V</em>{\text{O}}^{\text{*<strong>}}}^{\text{</strong>}} )</td>
<td>-0.26</td>
<td>-1.00</td>
</tr>
<tr>
<td>( {\text{Nb}<em>{\text{Zr}}^\text{′}: V</em>{\text{O}}^{\text{*<strong>}}}^{\text{</strong>}} )</td>
<td>0.25</td>
<td>0.00</td>
</tr>
</tbody>
</table>
The presence of the unpaired electrons in the \(\{\text{Nb}_{\text{Zr}}^{\prime\prime} : V_{\text{O}}\}^x\) and \(\{\text{Nb}_{\text{Zr}}^{\prime} : V_{\text{O}}\}^{**}\) clusters is evidence that the overall charge imposed on the system is being entirely concentrated on the Nb ion, and that the expected Nb charge states are indeed appearing in the clusters. Further to this, the average Nb-O bond lengths between the Nb ion and its 7 coordinating O ions (the 8th coordination site is the clustered oxygen vacancy) for each defect cluster, are plotted in Figure 6. The average bond length reduces linearly with the increased charge, again consistent with the applied charge localised on the Nb ion, increasing the attraction to the surrounding oxygen ions.

Table 2 shows the relaxation volumes of the various defects considered in this work. For the isolated defects, the more negative the Nb ion, the larger the defect volume. For all defects that have an overall charge in ZrO\(_2\) of less than 0 (i.e. Nb\(^{3+}\) and Nb\(^{2+}\)), a positive defect volume is predicted. Under
compressive stress, the larger defects are expected to exhibit an increased formation energy due to the strain exerted on the surrounding lattice. Thus, were a compressive stress applied to the simulations, as is present in the real oxide, larger defects are likely to be less favoured. This would suggest that under stress, the 5+ oxidation state would be more favourable for isolated defects. However, all \{Nb_{Zr}:V_{O}\} type defects and all but the most negative \{Nb_{Zr}:V_{O}:Nb_{Zr}\} clusters exhibit a negative relaxation volume. This suggests that under compressive stress, defect clustering may occur at concentrations far higher than predicted in the stress-free diagram presented in Figure 5.

The difference in predicted defect behaviour between tetragonal and monoclinic ZrO$_2$ can be largely explained by the difference in intrinsic defects present in the two phases, as shown in Figure 3. This suggests that Nb actually favours the 5+ oxidation state, but is able to occupy lower oxidation states in order to charge balance elevated intrinsic defect concentrations. While the intrinsic defect concentration in the tetragonal Brouwer diagrams may be artificially elevated due to the high temperature used, to compensate for the lack of applied stress, the predicted Nb defect behaviour suggests that the lower oxidation states of Nb can only exist when compensating for an elevated oxygen vacancy concentration. It follows, therefore, that the oxide measured in the various XANES investigations is consistent with it containing regions of highly defective tetragonal phase ZrO$_2$.

Oxygen vacancies are known to act as a tetragonal phase stabilisation mechanism. It follows, therefore, that close to the metal/oxide interface where the oxygen partial pressure is extremely low, the resulting high oxygen vacancy concentration would lead to tetragonal phase stabilisation. Under
these conditions, Nb is predicted to occupy a lower charge state in order to mitigate the excessive positive charge introduced by the high oxygen vacancy concentration. A corrosion model developed by Couet et al. [16], with the aim of explaining the unique parabolic corrosion behaviour and low HPUF of Zr-Nb alloys, suggests that as corrosion progresses a positive space charge builds-up in the oxide layer due to the lower mobility of oxygen vacancies compared to electrons through ZrO$_2$. As the space charge builds-up, both oxygen vacancy and electron mobility are inhibited, leading to sub-parabolic corrosion kinetics and an increased HPUF. The model suggests that by occupying lower oxidation states, Nb is able to mitigate this space charge and allow the corrosion kinetics to approach parabolic, while also reducing HPUF. The results, shown in Figure 5, predict that in the tetragonal phase, this process can occur and may be the mechanism through which Zr-Nb alloys exhibit their unique corrosion and HPUF properties. However, the results shown in Figure 4 suggest that this process does not occur in the monoclinic phase, due to the significantly lower intrinsic defect concentrations.

XRD studies performed by Wei et al. [21] demonstrated that the tetragonal phase fraction of the oxide layer drops significantly during first transition. Figure 7 shows the weight gain and measured instantaneous HPUF during the autoclave corrosion of ZIRLO sheet; the HPUF is shown to increase steadily as corrosion progresses and then drop significantly as the oxide layer passes through transition. So, while in the tetragonal phase, Nb has been shown to occupy oxidation states between 2+ and 5+, in the monoclinic phase only the 5+ oxidation state is seen. Thus, any Nb in a lower state will oxidise to 5+ as the ZrO$_2$ transforms from tetragonal to monoclinic during transition. This
process will inject electrons into the oxide layer, temporarily increasing the electrical conductivity. The electrical conductivity of the oxide layer is key to the HPUF, since the closer to the oxide/water interface that recombination between H$^+$ ions and electrons occurs, the less likely it is that hydrogen will diffuse all the way through the oxide layer to the oxide/metal interface. The oxidation of Nb ions, as tetragonal ZrO$_2$ transforms to monoclinic, is proposed as a possible explanation for the reduction in instantaneous HPUF observed during transition.

4. Conclusions

1. For both monoclinic and tetragonal phases at 635 K Nb$_{Zr}^\bullet$ is the favoured Nb defect across all oxygen partial pressures.

2. Zr vacancies are shown to be the dominant charge balancing mecha-
anism for $\text{Nb}^*_{\text{Zr}}$ in monoclinic $\text{ZrO}_2$, not electrons, suggesting that contrary to previous assumptions, Nb does not act as an n-type dopant in the oxide layer.

3. Brouwer diagrams for the tetragonal phase plotted at 1500 K, to account for the lack of stress stabilisation, show significantly elevated concentrations of intrinsic defects, particularly $V^*_{\text{O}}$.

4. The high temperature t-$\text{ZrO}_2$ diagram predicts that at low oxygen partial pressures, $\text{Nb}^*_{\text{Zr}}$ becomes the dominant Nb defect, with $\text{Nb}''_{\text{Zr}}$ also present.

5. $\{\text{Nb}_{\text{Zr}}:V_{\text{O}}\}$ clusters containing $\text{Nb}^*_{\text{Zr}}$ and $\text{Nb}''_{\text{Zr}}$ are predicted to occur at low oxygen partial pressures, but are not the dominant Nb defect type.

6. $\{\text{Nb}_{\text{Zr}}:V_{\text{O}}\}$ and $\{\text{Nb}_{\text{Zr}}:V_{\text{O}}:\text{Nb}_{\text{Zr}}\}$ clusters containing $\text{Nb}^*_{\text{Zr}}$ and $\text{Nb}''_{\text{Zr}}$ have negative defect volumes, suggesting that under compressive stress defect clustering may be more significant.

7. Lower oxidation states of Nb are able to mitigate the build up of space charge, increasing oxygen vacancy and electron mobility and thus allowing corrosion kinetics to approach parabolic and the HPUF to be reduced.

8. The oxidation of lower charge state Nb ions as tetragonal phase $\text{ZrO}_2$ transforms to monoclinic is proposed as a mechanism for the drop in instantaneous HPUF during transition.

5. Acknowledgements

Bell, Grimes and Wenman would like to acknowledge Rolls-Royce for the financial support for the modelling work as part of the Westinghouse led MUZIC-2 research programme and for the computational resources provided.
by the Imperial College High Performance Computing Centre.
Table 2: Defect volumes for Nb ions and Nb clusters calculated from DFT simulation results using the Aneto software package [48].

<table>
<thead>
<tr>
<th>ZrO$_2$ phase</th>
<th>Defect</th>
<th>Volume (Å$^3$)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Nb$_{Zr}^{''}$</td>
<td>25.94</td>
</tr>
<tr>
<td>Monoclinic</td>
<td>Nb$_{Zr}^{'}$</td>
<td>12.57</td>
</tr>
<tr>
<td></td>
<td>Nb$_{Zr}^{x}$</td>
<td>-2.72</td>
</tr>
<tr>
<td></td>
<td>Nb$_{Zr}^{*}$</td>
<td>-17.05</td>
</tr>
<tr>
<td></td>
<td>Nb$_{Zr}^{''}$</td>
<td>33.48</td>
</tr>
<tr>
<td></td>
<td>Nb$_{Zr}^{'}$</td>
<td>15.56</td>
</tr>
<tr>
<td></td>
<td>Nb$_{Zr}^{x}$</td>
<td>-1.03</td>
</tr>
<tr>
<td></td>
<td>Nb$_{Zr}^{*}$</td>
<td>-17.77</td>
</tr>
<tr>
<td>Tetragonal</td>
<td>{Nb$_{Zr}^{''}$:V$_O^{**}$}$^x$</td>
<td>-4.58</td>
</tr>
<tr>
<td></td>
<td>{Nb$_{Zr}^{'}$:V$_O^{**}$}$^*$</td>
<td>-20.71</td>
</tr>
<tr>
<td></td>
<td>{Nb$_{Zr}^{x}$:V$_O^{<strong>}$}$^{</strong>}$</td>
<td>-37.82</td>
</tr>
<tr>
<td></td>
<td>{Nb$_{Zr}^{<em>}$:V$_O^{<strong>}$}$^{</strong></em>}$</td>
<td>-55.84</td>
</tr>
<tr>
<td></td>
<td>{Nb$_{Zr}$:V$<em>O$:Nb$</em>{Zr}$}$^{**}$</td>
<td>-33.63</td>
</tr>
<tr>
<td></td>
<td>{Nb$_{Zr}$:V$<em>O$:Nb$</em>{Zr}$}$^{*}$</td>
<td>-13.81</td>
</tr>
<tr>
<td></td>
<td>{Nb$_{Zr}$:V$<em>O$:Nb$</em>{Zr}$}$^x$</td>
<td>-4.35</td>
</tr>
<tr>
<td></td>
<td>{Nb$_{Zr}$:V$<em>O$:Nb$</em>{Zr}$}$'$</td>
<td>26.38</td>
</tr>
<tr>
<td></td>
<td>{Nb$_{Zr}$:V$<em>O$:Nb$</em>{Zr}$}$''$</td>
<td>37.05</td>
</tr>
</tbody>
</table>


Implications for H pick-up and hydriding of Zircaloy-2 and Zircaloy-4. 


